RECTIFIER, up to 150V, 1.8A, 30ns

1N6073 1N6074

1N6075

FF10 FF15

January 7, 1998

TEL:805-498-2111 FAX:805-498-3804 WEB:http://www.semtech.com

# AXIAL LEADED HERMETICALLY SEALED SUPERFAST RECTIFIER DIODE

- · Very low reverse recovery time
- Hermetically sealed in Metoxilite fused metal oxide
- Low switching losses
- Low forward voltage drop
- Soft, non-snap off, recovery characteristics

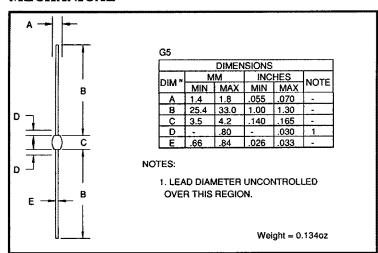
## QUICK REFERENCE DATA

- $V_R = 50 150V$
- $I_F = 1.8A$
- $t_{rr} = 30nS$
- $V_F = 1.2V$

# ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

	Symbol	1N6073 FF05	1N6074 FF10	1N6075 FF15	Unit
Working reverse voltage	V <sub>RWM</sub>	50	100	150	V
Repetitive reverse voltage	V <sub>RRM</sub>	50	100	150	V
Average forward current (@ 55°C, lead length = 0.375")	I <sub>F(AV)</sub>	4	1.8	<del>_</del>	Α
Repetitive surge current (@ 55°C, lead length = 0.375")	I <sub>FRM</sub>	4	<del></del>		Α
Non-repetitive surge current (tp = 8.3ms, @ V <sub>R</sub> & Tj <sub>max</sub> )	I <sub>FSM</sub>	<del></del>	— 35.0 —	<del></del>	A
Storage temperature range Operating temperature range	T <sub>STG</sub> T <sub>OP</sub>	•	-65 to +150 -65 to +150		°C
		4			`

#### **MECHANICAL**



These products are qualified to MIL-S-19500/503.

They can be supplied fully released as JAN, JANTX, and JANTXV versions.

These products are qualified in Europe to DEF STAN 59-61 (PART 80)/029 available to F and FX levels.

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# ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise specified)

	Symbol	1N6073 FF05	1N6074 FF10	1N6075 FF15	Unit
Average forward current max. (pcb mounted; T <sub>A</sub> = 55°C) for sine wave for square wave (d = 0.5)	I <sub>F(AV)</sub> I <sub>F(AV)</sub>	<b></b>	0.85 0.90		A A
Average forward current max. $T_L = 70^{\circ}\text{C}$ ; $L = 0$ ". $T_L = 55^{\circ}\text{C}$ ; $L = 3/8$ "	I <sub>F</sub> (AV)		3.0		A
for sine wave for square wave I <sup>2</sup> t for fusing (t = 8.3mS) max.	IF(AV) I <sub>F</sub> (AV) I <sup>2</sup> t	-	1.7 1.8 5.0		A A A <sup>2</sup> S
Forward voltage drop max. @ IF = 1.5A, $T_j = 25^{\circ}C$	V <sub>F</sub>	<b>-</b>	— 1.2 <del>—</del>		v
Reverse current max.  @ $V_{RWM}$ , $T_j = 25^{\circ}C$ @ $V_{RWM}$ , $T_j = 100^{\circ}C$	I <sub>R</sub> IR	<b>—</b>	<u> </u>	<b></b>	μA μA
Reverse recovery time 0.5A I <sub>F</sub> , 1.0A I <sub>R</sub> , 0.25A I <sub>RR</sub> .	t <sub>rr</sub>	4	<del></del> 30 <del></del>		nS
Junction capacitance typ. @ $V_R = 5V$ , $f = 1MHz$	C <sub>j</sub>	<b>-</b>	28		ρF

### THERMAL CHARACTERISTICS

	Symbol	1N6073 FF05	1N6074 FF10	1N6075 FF15	Unit
Thermal resistance - junction to lead Lead length = 0.375" Lead length = 0.0" Thermal resistance - junction to amb. on 0.06" thick pcb. 1 oz. copper.	R <sub>OJL</sub> R <sub>OJL</sub> R <sub>OJA</sub>	-	46 — 13 — 95 —		°C/W °C/W °C/W

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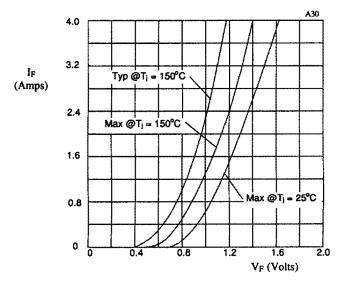


Fig 1. Forward voltage drop as a function of forward current.

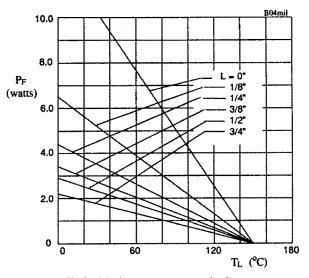


Fig 2. Maximum power versus lead temperature.

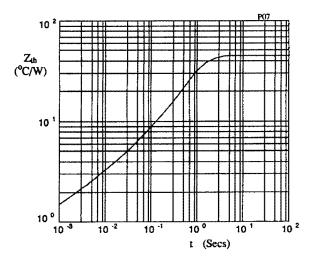


Fig 3. Transient thermal impedance characteristic.

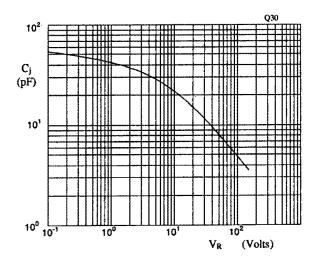


Fig 4. Typical junction capacitance as a function of reverse voltage.

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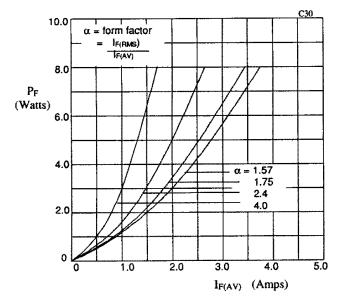


Fig 5. Forward power dissipation as a function of forward current, for sinusoidal operation.

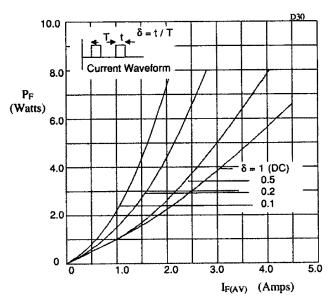


Fig 6. Forward power dissipation as a function of forward current, for square wave operation.

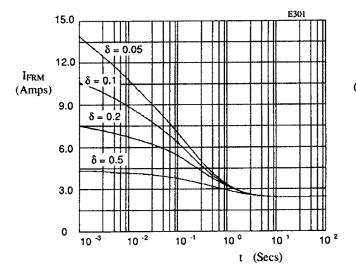


Fig 7. Maximum repetitive forward current as a function of pulse width at 55°C; R<sub>OJL</sub> = 45 °C/W; V<sub>RWM</sub> during 1 - δ.

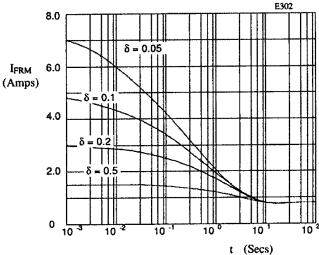


Fig 8. Maximum repetitive forward current as a function of pulse width at  $100^{\circ}$ C;  $R_{\theta JL} = 110^{\circ}$ C/W; V<sub>RWM</sub> during 1 - δ.